## NSN 5961-01-349-0231

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-349-0231
Inclosure Material:
Metal
Overall Length:
1.250 inches
Mounting Facility Quantity:
1
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
D0-4
Mounting Method:
Threaded stud
Features Provided:
Electrostatic sensitive and hermetically sealed case
Overall Width Across Flats:
Between 0.429 inches and 0.434 inches
Thread Size:
0.190 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
500.0 reverse voltage, instantaneous
Current Rating Per Characteristic:
15.00 amperes forward current, average
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius junction
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 tab, solder lug and 1 threaded stud
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0